

QCA75A/QCB75A40/60

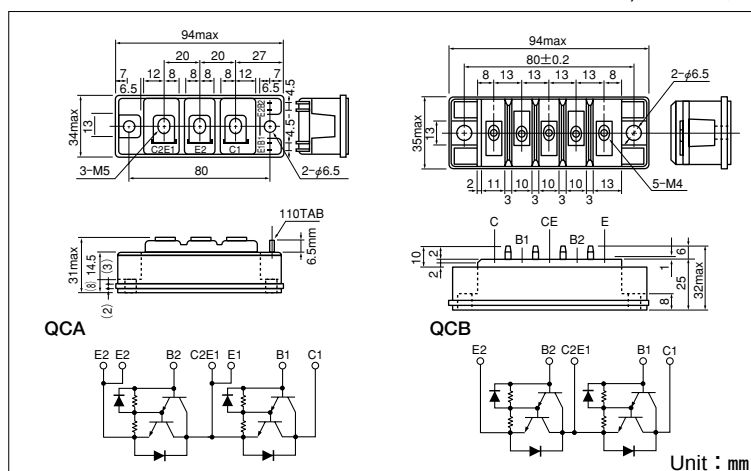
UL:E76102(M)

QCA75A and **QCB75A** are dual Darlington power transistor modules which have series-connected high speed, high power Darlington transistors. Each transistor has a reverse paralleled fast recovery diode.

- $I_C=75A$, $V_{CEX}=400/600V$
- Low saturation voltage for higher efficiency.
- Isolated mounting base
- V_{EBO} 10V for faster switching speed.

(Applications)

Motor Control (VVF), AC/DC Servo, UPS,
Switching Power Supply, Ultrasonic Application



■ Maximum Ratings

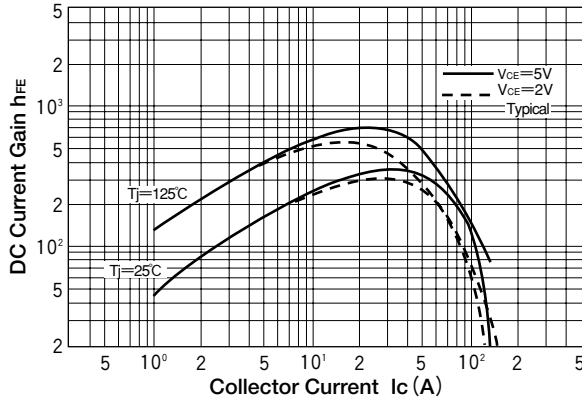
(Tj=25°C unless otherwise specified)

Symbol	Item		Conditions	Ratings		Unit
				QCA75A40 QCB75A40	QCA75A60 QCB75A60	
V _{CBO}	Collector-Base Voltage			400	600	V
V _{CEX}	Collector-Emitter Voltage		V _{BE} =−2V	400	600	V
V _{EBO}	Emitter-Base Voltage			10		V
I _C	Collector Current		() pw≤1ms	75 (150)		A
−I _C	Reverse Collector Current			75		A
I _B	Base Current			4.5		A
P _T	Total power dissipation		T _C =25℃	350		W
T _J	Junction Temperature			−40 to +150		℃
T _{stg}	Storage Temperature			−40 to +125		℃
V _{ISO}	Isolation Voltage		A.C.1minute	2500		V
	Mounting Torque	QCA75A	Mounting (M6)	Recommended Value 2.5-3.9 (25-40)	4.7(48)	N·m kgf·cm
			Terminal (M5)	Recommended Value 1.5-2.5 (15-25)	2.7(28)	
		QCB75A	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	2.7(28)	
			Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	1.5(15)	
				Mass	QCA75A/QCB75A	

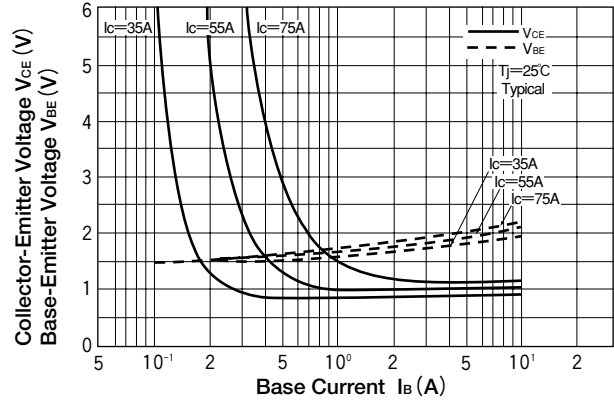
■ Electrical Characteristics

Symbol	Item		Conditions	Ratings		Unit
				Min.	Max.	
I _{CB} O	Collector Cut-off Current		V _{CB} =V _{CB} O		1.0	mA
I _{EB} O	Emitter Cut-off Current		V _{EB} =V _{EB} O		300	mA
V _{CEO} (SUS)	Collector Emitter Sustaning Voltage	QCA75A40 QCB75A40	I _C =1A	300		V
		QCA75A60 QCB75A60		450		
V _{CEX} (SUS)		QCA75A40 QCB75A40	I _C =15A, I _{B2} =-5A	400		V
		QCA75A60 QCB75A60		600		
h _{FE}	DC Current Gain		I _C =75A, V _{CE} =2V/5V	75/100		
V _{CE} (sat)	Collector-Emitter Saturation Voltage		I _C =75A, I _B =1A		2.0	V
V _{BE} (sat)	Base-Emitter Saturation Voltage		I _C =75A, I _B =1A		2.5	V
t _{on}	Switching Time	On Time	V _{CC} =300V, I _C =75A I _{B1} =1A, I _{B2} =-1A		2.0	μs
t _s		Storage Time			12.0	
t _f		Fall Time			3.0	
V _{ECO}	Collector-Emitter Reverse Voltage		-I _C =75A		1.4	V
R _{th(j-c)}	Thermal Impedance (junction to case)		Transistor part/Diode part		0.35/1.3	°C/W

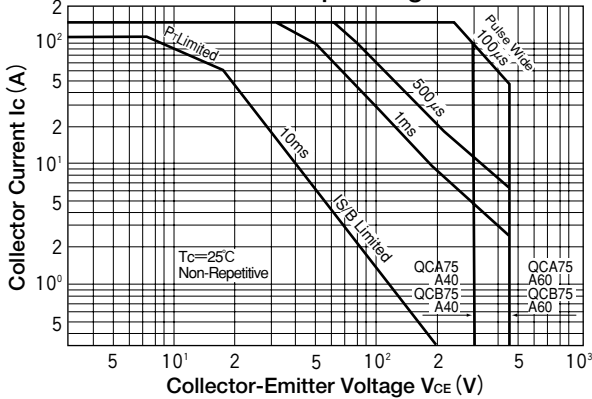
D.C. Current Gain



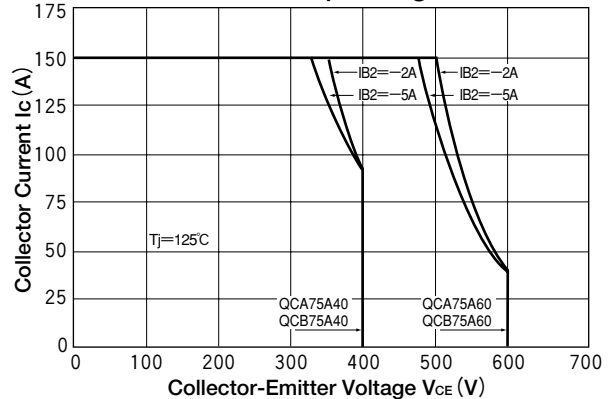
Saturation Characteristics



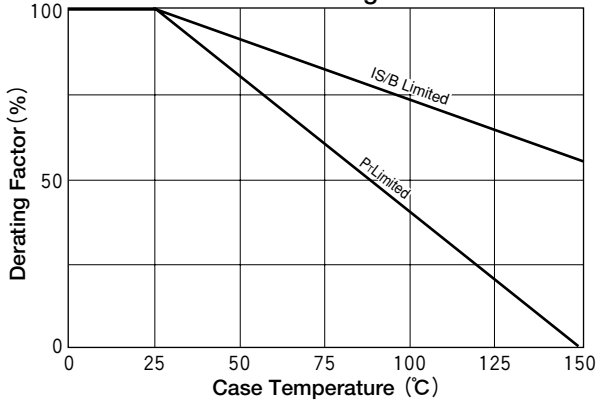
Forward Bias Safe Operating Area



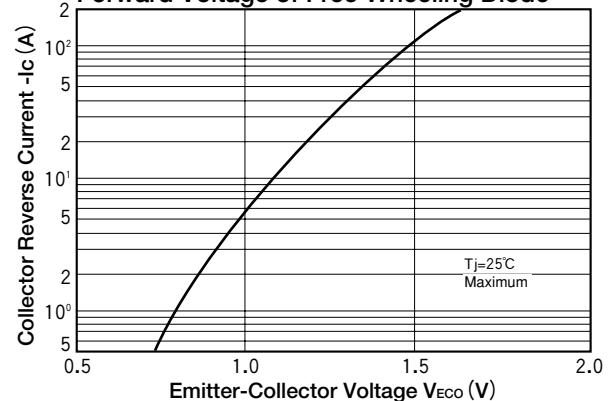
Reverse Bias Safe Operating Area



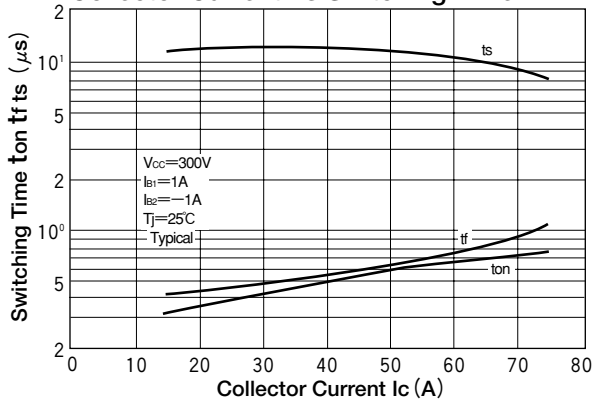
Collector Current Derating Factor



Forward Voltage of Free Wheeling Diode



Collector Current Vs Switching Time



Maximum Transient Thermal Impedance Characteristics

